J Sol-Gel Sci Technol (2011) 60:378–387 DOI 10.1007/s10971-011-2568-7

ORIGINAL PAPER

Sol-gel derived mesoporous Pt and Cr-doped WO₃ thin films: the role played by mesoporosity and metal doping in enhancing the gas sensing properties

Massimiliano D'Arienzo · Maurizio Crippa · Paolo Gentile · Claudio Maria Mari · Stefano Polizzi · Riccardo Ruffo · Roberto Scotti · Laura Wahba · Franca Morazzoni

Received: 21 February 2011/Accepted: 16 August 2011/Published online: 8 September 2011 © Springer Science+Business Media, LLC 2011

Abstract Mesoporous Cr or Pt-doped WO₃ thin films to be employed as ammonia gas sensors were prepared by a fast one-step sol-gel procedure, based on the use of triblock copolymer as templating agent. The obtained films were constituted by aggregates of interconnected WO₃ nanocrystals (20-50 nm) separated by mesopores with dimensions ranging between 2 and 15 nm. The doping metals, Pt and Cr, resulted differently hosted in the WO₃ mesoporous matrix. Chromium is homogeneously dispersed in the oxide matrix, mainly as Cr(III) and Cr(V) centers, as revealed by EPR spectroscopy; instead platinum segregated as Pt (0) nanoparticles (4 nm) mainly included inside the WO₃ nanocrystals. The semiconductor layers containing Pt nanoclusters revealed, upon exposure to NH₃, remarkable electrical responses, much higher than Cr-doped and undoped layers, particularly at low ammonia concentration (6.2 ppm). This behavior was attributed to the presence of Pt nanoparticles segregated inside the

Electronic supplementary material The online version of this article (doi:10.1007/s10971-011-2568-7) contains supplementary material, which is available to authorized users.

M. D'Arienzo (🖂) · M. Crippa · C. M. Mari · R. Ruffo · R. Scotti · L. Wahba · F. Morazzoni INSTM, Department of Materials Science, University of Milano-Bicocca, Via R. Cozzi 53, 20125 Milan, Italy e-mail: massimiliano.darienzo1@unimib.it

P. Gentile

Department of Geological Sciences and Geotechnologies, University of Milano Bicocca, Piazza della Scienza 4, 20126 Milan, Italy

S. Polizzi

semiconductor matrix, which act as catalysts of the N–H bond cleavage, decreasing the activation barrier in the ammonia dissociation. The role of the mesoporous structure in influencing the chemisorption and the gas diffusion in the WO_3 matrix appeared less decisive than the electronic differences between the two examined doping metals. The overall results suggest that a careful combination between mesoporous architecture and metal doping can really promote the electrical response of WO_3 toward ammonia.

Keywords Pt and Cr—doped $WO_3 \cdot Mesoporous$ thin film \cdot Gas sensors \cdot Morphological, electronic and electrical properties

1 Introduction

Semiconducting metal oxides have been studied for some decades as sensing materials, in order to detect hazardous gases [1–8]. The mechanism of the metal-oxide sensors is based on the change of electrical conductance in response to the introduction of a small concentration of reducing gas, which reacts with the oxygen species at the oxide surface [1, 4, 5]. Many extensive studies, mainly concerning SnO₂, widely investigate the dependence of the electrical response on both the electronic and morphological properties of the semiconductor [9–15]. The sensing mechanism towards different gases, H₂ [16], CO [17] and NO₂ [18] was also suggested.

Several mechanistic details were achieved thank to the use of the sol-gel synthetic approach, whose attitude to give nano-materials with very reactive surfaces and controlled particle size and porosity, allows to obtain samples with enhanced electrical response [19–22].

Department of Molecular Sciences and Nanosystems, Università Ca' Foscari Venezia, and INSTM, UdR Venezia, Via Torino 155/b, 30172 Venezia, Italy

In fact, the performances of semiconductor based sensors are determined by the surface interaction of the oxide with the analyte gas [1–5]. Specifically fast gas diffusion rate through the sensing layer and effective charge transfer between the grains require oxide grain size of nanometric dimensions, comparable to the thickness of the space-charge region [24, 25]. Moreover, high interconnectivity between the particles is needed to facilitate the electronic charge transport [9, 10]; high surface area to favor the gas-oxide interaction and porous structure to improve the gas diffusion throughout the layer [9]. In addition the sensor response can be significantly enhanced by homogeneously dispersing noble metals centres into the oxide matrix, such as Pt, Pd, Ag, which act as catalysts of the chemical interaction between gas molecules and the semiconductor [11, 15].

In this frame, our group prepared nanostructured thin films of transition metal doped SnO_2 by the sol-gel method and demonstrated the improving effect of the particle nanosize and of the homogeneously dispersed doping metal on the oxide sensing properties [11, 15]. The dependence of electrical response on the film morphology, on the oxidation state of the metals, as well as the electron transfer at the interface gas/metal/oxide were also investigated. The metal and oxygen defects responsible for the variations in the semiconductor resistance were revealed by electron spin resonance measurements [11, 18].

Moreover, in order to better detail the effect of the porous structure on the oxide sensing properties, three dimensionally ordered macroporous materials (3DOM), specifically Pt-doped SnO₂ inverted opal films, were synthesized by alkoxide-based sol-gel processes [10, 11]. The self assembled ordered array of colloidal polymeric microspheres was used as the template; the interstices were filled with metal alkoxide solution, then hydrolyzed and densified. The obtained inverted opal architecture is constituted of macropores connected through holes, resulting from the contact between the template spheres, surrounded by strongly interconnected nanocrystalline particles. These morphological features guarantee high surface chemisorption and easy gas diffusion. Recently, our group proposed an innovative one-step sol-gel preparation of Pt doped SnO₂ as inverse opal thin films by dip-coating deposition, to easily obtain three dimensional ordered macroporous metal oxides with high surface area and homogeneous dopant metal distribution. The procedure enables the selfassembled formation of closely-packed PS template array and the simultaneous infiltration of the precursors into the voids of the structure, making it possible to obtain the oxide solid skeleton around the spheres in one-step [15].

Among semiconductor metal-oxides, WO_3 has been also considered as one of the most promising materials for toxic gas detection, in particular for ammonia detection [26]. An extensive scientific and engineering research is still active on this topic, focused on optimizing the sensing properties: electrical response, response rate, gas selectivity and long-term stability [26, 27]. In this context, the tailoring of the morphology and an effective doping method of the oxide matrix still remain important challenges.

We recently studied the behaviour of sol–gel prepared WO_3 films as NH_3 sensor and investigated the role Cr, Cu and V dopant, in enhancing the electrical response and in avoiding the resistance overshooting effects observed in undoped WO_3 [28, 29]. However, the preparation method adopted was relatively time consuming and the sensor performances were evaluated only under high ammonia concentration (500 ppm). Furthermore, no doping with noble metal (such as Pt), which in principle can enhance the NH_3 dissociation and promotes the response, was carried out.

In this paper, we report a fast and tailored sol-gel onestep procedure to prepare Cr and Pt-doped WO₃ mesoporous thin films for ammonia gas sensing, based on the use of polyalkyleneoxide triblock copolymer as the templating agent. The purpose was to study the effect of the oxide porous morphology and of the metal homogeneous doping on the sensing properties towards NH₃. The morphology of the WO₃ films and the electronic properties of the doping metal centers were studied by electron microscopy and EPR spectroscopy, in order to suggest a mechanism for the variations of electrical properties in the presence of NH₃. Finally the electrical response of the WO₃ layers was discussed in terms of conductance regime under different gas concentrations, in order to achieve optimum balance between the intensity and the reproducibility of sensor performances. Results supported the validity of the synthesis method here reported to supply promising nanomaterials for the detection of ammonia even at low concentration.

2 Experimental section

2.1 Chemicals

Poly(alkylene oxide) block copolymer designated (HO(CH₂ CH₂O)₂₀(CH₂CH(CH₃)O)₇₀(CH₂CH₂O)₂₀OH (EO₂₀PO₇₀EO₂₀), Pluronic P123); tungsten hexachloride, WCl₆ 99.9%; chromium(III) nitrate nona hydrate Cr(NO₃)₃·9H₂O 99%, bis-(acetylacetonate)platinum(II), Pt(acac)₂ 97% and absolute ethanol (99.9%) were all purchased from Aldrich and used without further purification.

2.2 Preparation of precursor suspensions of Pt- and Cr-doped WO₃ sol-gel film and film deposition

The precursor suspensions for the deposition of Pt- and Cr-doped WO₃ sol-gel films, were prepared according to a

previously reported procedure [23]. The doping was carried out by direct addition of the dopant metal precursor to the reaction solution.

In a typical preparation the copolymer $EO_{20}PO_{70}EO_{20}$ (1 g) was dissolved in ethanol (10 mL) under magnetic stirring. Then WCl₆ (400 mg) was added under a N₂ atmosphere, and the resulting dark blue solution was vigorously stirred for 30 min. Pt (Pt:W molar ratio 0.025) or Cr doping procedure (Cr:W molar ratio 0.025) was carried out by adding the proper amount of Pt(acac)₂, or Cr(NO₃)₃·9H₂O, respectively, to the WO₃ precursor suspension. The obtained solution was stirred at room temperature in air for 24 h, until the sol phase reached a suitable viscosity (~2.5 ± 0.3 cSt) for the dip-coating deposition.

Sol–gel films were deposited in air by dip-coating (0.8 cm/min) on Suprasil quartz slides (20×20 mm, 0.25 mm thickness) and dried in air for about 10 min at room temperature. The above cycle was repeated three times, then the film was annealed at 450 °C (heating rate 2 °C min⁻¹) in air stream (80 cm³ min⁻¹) for 5 h, in order to fully decompose the polymeric template and all the organic remnants.

Since XRD, BET and EPR analysis of films are difficult to be performed with high accuracy, these characterizations were performed on powders. To gain pure and doped WO₃ nanopowders, the sol phase used for film deposition was gelled in an open Petri dish at 100 °C in air for 24 h until the xerogel was obtained. This later was calcined under the same conditions used for films in order to completely remove the organics and obtain a green crystalline WO₃ powder.

2.3 Morphological characterization

XRD analysis was performed on WO₃ powdered samples. X-ray diffraction (XRD) patterns were collected with a Brucker D8 Advance (Cu K α radiation) in the range 20–80° 2 θ (2 θ step 0.025°, count time of 2 s per step).

Specific surface area (SSA) by BET method [28], desorption cumulative pore volume (DCPV) and pore size distribution of micro- and mesopores (<50 nm) by BJH method [29] were measured by nitrogen physisorption using Quantachrome Autosorb-1 apparatus. Cr-doped and Pt-doped WO₃ powder samples were evacuated at 200 °C for 16 h before the analysis.

Scanning electron microscopy (SEM) measurements of the films were performed by a Vega TS5136 XM Tescan microscope in a high-vacuum configuration. The electron beam excitation was 30 kV at a beam current of 25 pA, and the working distance was 12 mm. In this configuration the beam spot was 38 nm. Prior to SEM analysis, samples were gold-sputtered. The average thickness of sol–gel derived WO₃ thin films was measured by observing cross-section SEM images of the layers.

High-resolution transmission electron microscopy (HRTEM) and electron diffraction (ED) were performed using a Jeol 3010 apparatus operated at 300 kV with a high-resolution pole piece (0.17 nm point-to-point resolution) and equipped with a Gatan slow-scan 794 CCD camera. Samples were obtained by removing a film portion from the substrates in order to obtain a fine powder sample, then suspended in 2-propanol. A 5 μ L drop of this suspension was deposited on a holey carbon film supported on a 3 mm copper grid for TEM investigation.

2.4 EPR characterization

The electron paramagnetic resonance (EPR) investigation was performed by a Bruker EMX spectrometer working at the X-band frequency and equipped with an Oxford cryostat operating in the range of temperature 4–298 K.

Cr-doped WO₃ powders were inserted into quartz glass tubes connected both to a vacuum pumping system and to a controlled gas feed (Synthetic Air).

Spectra were recorded under vacuum conditions (10^{-2} mbar) at 130 K, on Cr (2%) doped WO₃ exposed for 60 min to 20 mbar of air at 250 °C, in order to reproduce the conditions of the electrical measurement (see Sect. 2.5).

Modulation frequency was 100 kHz, modulation amplitude 5 gauss, and microwave power 20 mW. The g values were calculated by standardization with α, α' -diphenyl- β -picryl hydrazyl (DPPH). Care was taken in order to always keep the most sensitive part of the EPR cavity (1 cm length) filled.

2.5 Electrical measurements

Suprasil quartz slides were equipped, before film deposition, with two gold current collectors (20 mm) deposited at a distance of about 2 mm from each other by the dc sputtering technique. Then the samples were placed in a quartz chamber sited in an oven, and the measurements were performed at different temperatures, ranging from 200 to 325 °C. The electrical resistance was measured by a programmable electrometer controlled by a PC. To dynamically reproduce environmental conditions in a controlled and reproducible way, a system based on volumetric gas mixing through mass flow controllers and certified bottles was used. The sensing element was initially equilibrated in air flow (100 mL min⁻¹) at the selected temperature, then NH₃ (range 6.2-74 ppm)/air mixture was introduced (100 mL min⁻¹) up to equilibrium conditions. The different gas mixtures were obtained by dilution of the starting NH₃ (74 ppm)/air mixture using mass flow

controllers. The initial resistance conditions of the film were restored by air equilibration, before again introducing the NH₃/air mixture. The electrical response (S) is defined as the ratio between the film resistance under flowing air, RAIR, and under flowing NH3/air mixture, RMIX, respectively (S = R_{AIR}/R_{MIX}).

3 Results and discussion

3.1 Structural and morphological characterization

XRD and BET analysis were performed on WO₃ powdered samples, as the film characterization is difficult to be performed with high accuracy (see Sect. 2).

XRD patterns of Cr-doped WO₃ powders are shown in Fig. 1. The broadening of the diffraction peaks suggests that the oxide is composed of nanocrystals. The obtained phase can be indexed as monoclinic, in fact the diffractogram shows the (200), (020), and (002) reflections (Fig. 1b) with similar intensities, precisely indicating the type of monoclinic structure (spacegroup: P21/n, a = 0.7297 nm, b = 0.7539 nm, c = 0.7688 nm, $\beta = 90.91^{\circ}$, JCPDS 43-1035). Identical diffraction patterns were obtained for pure and Pt-doped WO₃ powders.

Cr and Pt-doped WO₃ nanopowders resulted mesoporous in the nitrogen physisorption measurements, showing type IV Brunauer isotherm and a broad monomodal pore size distribution centered at 20 nm. As an example, the adsorption-desorption isotherms and the corresponding pore-size distribution of Pt-doped WO₃ powders are shown in Fig. 2. According to the t-plot (not showed), no micropores were detected. Cr and Pt-doped WO₃ sol-gel powders exhibit a specific surface area (SSA) of 39.1 and 45.4 m² g⁻¹; a DCPV of 0.21 and 0.19 cm³ g⁻¹, respectively.

Scanning electron microscopy (SEM) investigations were performed on both undoped and transition metaldoped WO₃ films. The average thickness of sol-gel derived





0.008

120

Fig. 2 Adsorption/desorption isotherm at liquid nitrogen for Ptdoped WO₃ sol-gel powders. Curves correspond to type IV isotherm with capillary condensation in the mesopores. Inset pore size distribution

WO₃ thin films was estimated by observing cross-section images of the layers and resulted in the range of $540-620 \pm 15$ nm (see Supporting Information, Fig. S1). Top view SEM micrographs of Pt-doped WO₃ film (Fig. 3) revealed the presence of porous aggregates of oxide nanoparticles (Fig. 3b). No large cracks were detectable and films with extensive homogeneity were obtained (Fig. 3a). Similar images were obtained for Cr-doped and also for bare WO₃ films (not shown), confirming that doping by transition metal ions does not affect the film morphology.

TEM images of Pt-doped and Cr-doped WO₃ sol-gel films are shown in Fig. 3. WO₃ aggregates are constituted of irregularly shaped interconnected nanocrystals (Fig. 4a, b) with a broad size distribution ranging from 20 to 50 nm, when the statistics is applied to about 150 particles. No amorphous phases and internal defects or pores were detectable. Higher magnification reveals that WO₃ nanoparticles (Fig. 4c, d) are separated by small







Fig. 3 SEM micrographs of Pt-doped WO3 sol-gel films showing large porous aggregates

mesopores with dimensions ranging between 5 and 15 nm, in agreement with the results obtained by nitrogen physisorption. Unexpectedly, Pt-doped WO₃ films show well detectable Pt metal nanocrystals; some of those lie at the surface, but the most are included inside the WO₃ matrix (Fig. 4d). These Pt particles appear to be distributed throughout the whole layer. Conversely, Cr-doped films are exempt of metal particles, suggesting dopant dispersion in the oxide matrix without any evident segregation.

Finally, the selected-area electron diffraction (SAED) patterns collected for Cr-doped and Pt-doped WO₃ (inset Fig. 4a, b) confirm the monoclinic structure of the oxide nanocrystals already revealed by powder diffraction. TEM analysis performed on undoped WO₃ sol–gel films gave analogous results (Fig. S2 Supporting Information).

High-resolution (HRTEM) images of Cr-doped (Fig. 4e) and Pt-doped WO₃ (Fig. 4f) samples evidence that the lattice fringes of the nanocrystals have a spacing of 3.79 Å, which reasonably matches the interplanar distance of the (200) plane of the monoclinic tungsten trioxide (ICDD 71-0131).

Inset in Fig. 4f provides insight into the structure of the spherical Pt metal nanoparticles observed in Pt-doped samples (Fig. 4d, f). Pt particles have diameter of about 4 nm and calculated interplanar spacing of 2.25 Å (not shown), in agreement with the (111) crystallographic plane of Pt (JCPDS 04-0802).

It appears that Pt ions of the precursor solution are reduced within the WO_3 lattice, at variance with Cr ions, as expected, and aggregate into clusters, probably favoured by the possibility of moving through the channels of the WO_3 perovskite open structure.

3.2 EPR investigation

While zerovalent Pt was easily detectable by the presence of metal nanoparticles, no information about the electronic states of Cr centers became evident.

Considering that Cr centers can in principle give rise to paramagnetic electronic states, an Electron Paramagnetic Resonance (EPR) investigation was performed on Cr-doped WO₃ powders, after exposure to 20 mbar of synthetic air at 250 °C, this condition simulating the operative sensor temperature (see the next section).

Figure 5 shows the spectra recorded at 130 K after sample evacuation (10^{-2} mbar) . The resonance lines are similar to those previously reported by us for differently prepared Cr-doped WO₃ samples and attributed to β Cr species (Cr₂O₃ like centers), δ Cr species (tetragonally distorted Cr(III) centers), γ Cr species (Cr(V) centers) [30, 31]. The total amount of paramagnetic centers is about 14% of the nominal Cr content (2%) and assesses that a significant part of chromium is in an oxidized paramagnetic electronic state.

3.3 Electrical measurements

WO₃ is a n-type semiconductor oxide, whose resistance decreases under NH_3 and increases under air. Its electrical response to NH_3 is associated with specific reactions at the gas-oxide interface. In previous works we suggested that, in the first stage of the reaction, ammonia molecules chemisorb on the Lewis and Brønsted acidic sites of WO₃ surface and undergo dehydrogenation through the capture of hydrogen atoms by the oxygen lattice centers (O₀) [28, 29]. Hydroxyl



Fig. 4 TEM and HRTEM images of Cr-doped (a, c, e) and Pt-doped (b, d, f) WO₃ sol-gel films. *Insets* in figure **a**, **b** report the SAED patterns of the Cr and Pt-doped WO₃ nanomaterials. *Inset* in figure **f** shows the magnification of a Pt spherical nanoparticle anchored to the WO₃ surface

groups and NH_{3-n}^{n-} species (n = 1, 2, 3) are produced following reaction 1:

$$2NH_3 + 6O_O \rightleftharpoons 2NH_{3-n}^{n-} + 2nO_OH + (6-2n)O_O$$
(1)

 NH_{3-n}^{n-} species successively interact between them leading to the formation of molecular nitrogen

(reaction 2A). Otherwise, they can react with oxygen centers to form nitrogen monoxide (Reaction 2B), which is the favored path in an oxygen-containing atmosphere. Finally, NH_{3-n}^{n-} species may reduce NO to N₂O by reaction (2C) [30, 31].

$$\longrightarrow N_2 + 6O_0H + 6e^- \rightleftharpoons N_2 + 3H_2O + 3O_0 + 6e^-$$

(2A)



Fig. 5 EPR spectra recorded at 130 K and $p < 10^{-2}$ mbar of Crdoped WO₃ powders annealed in air (20 mbar) at 250 °C. In large sweep spectra **a** Cr species are labelled as δ , β and γ . **b** Enlarged spectra in the region of the Cr(V) resonances (γ species) and corresponding *g* tensor values

 $\longrightarrow 2\text{NO} + 6\text{O}_{\text{O}}\text{H} + 10\text{e}^{-} \rightleftharpoons 2\text{NO} + 3\text{H}_{2}\text{O} + 3\text{O}_{0} + 10\text{e}^{-}$ (2B)

$$\stackrel{+2\text{NO}}{\rightarrow} 2\text{N}_2\text{O} + 6\text{O}_0\text{H} + 6\text{e}^- \rightleftharpoons 2\text{N}_2\text{O} + 3\text{H}_2\text{O} + 3\text{O}_0 + 6\text{e}^-$$
(2C)

All these processes generate electrons and increase the WO_3 conductance.

In the presence of doping metal, we suggested that the metal centers trap (reaction 3) the electrons derived from reactions (2A-2C), and right hand shift all processes 2A-2C. This allows the production of further electrons, increasing the electrical response [15]:

$$\mathbf{M}^{m+} + \mathbf{n} \ \mathbf{e}^{-} \to \ \mathbf{M}^{(m-n)+} \quad (m, n = 1, 2, 3, 4)$$
 (3)

Transition metal doped WO_3 mesoporous films are in principle expected to combine the effects due to the metal electronic sensitizer with those of the porous morphology, suitable for fast gas diffusion through the sensing layer and easy accessibility to the surface active sites.

The electrical response of doped and undoped WO_3 films was evaluated by measuring the resistance variation under alternating air and NH₃/air flows. Examples of resistance variation at different concentrations of NH₃/air mixture for Pt-doped and Cr-doped WO_3 samples are shown in Fig. 6.

The sensor response was evaluated as $S = R_{AIR}/R_{MIX}$, where R_{AIR} is the resistance under air and R_{MIX} is the electrical resistance under NH₃/air gas. The variations of the electrical response were taken at different temperatures (200–325 °C) and for different NH₃ concentrations (6.2–74 ppm) in dry air. Figure 7 reports the electrical responses as a function of the operating temperatures for undoped, Cr-doped, and Pt-doped WO₃ films under different NH₃ concentrations.

All samples showed a similar temperature-dependence of the sensitivity, marked by a maximum at 250 $^{\circ}$ C and by a decrease at the highest temperatures. At each NH₃

Fig. 6 Examples of electrical responses at T = 300 °C of (*left*) Pt-doped and (*right*) Cr-doped sol-gel WO₃ films to different concentrations of NH₃ in synthetic air





Fig. 7 Temperature dependence of sensor response of a Pt-doped; b Cr-doped and c pure WO_3 films at different NH_3 concentration in dry air

concentration, Pt-doped samples display higher electrical responses compared to Cr-doped and undoped ones. In particular, Pt-doped WO₃ layers show the best performances at 250 °C under 74 ppm of NH₃ (S = 47), with a significant response even at 6.2 ppm (S = 5), the lowest

 Table 1 Electrical sensitivity and recovery times detected for Ptdoped WO₃ sol-gel films

| Temperature (°C) | $S = R_{AIR}/R_{MIX}$ under NH ₃ (74 ppm)/air | $S = R_{AIR}/R_{MIX}$ under NH ₃ (6.2 ppm)/air | Recovery times from NH ₃ (74 ppm)/air |
|---------------------|--|---|--|
| 200 | 12.0 | 2.5 | >20 h |
| 225 | 30 | 3.2 | ≈ 10 h |
| 250 | 47 | 5.0 | $\approx 5 h$ |
| 275 | 19.6 | 1.9 | $\approx 2 h$ |
| 300 | 7.4 | 1.4 | \approx 50 min |
| 325 | 2.13 | 1.1 | $\approx 10 \text{ min}$ |

NH₃ concentration. The electrical response for the Ptdoped WO₃ films and the corresponding recovery times at the highest ammonia concentration are reported in Table 1. It is interesting to note that increasing the temperature till 300-325 °C, Pt-doped films display relatively short recovery times (~50–10 min), which become significantly higher when the temperature is below 250 °C (see Table 1).

The maximum shaped trend of the electrical sensitivity is probably caused by a balance between two opposite effects. In fact, upon heating, ammonia reactions (2A–2C) at the oxide surface become faster and the response increases. On the other hand, NO, a side product of ammonia oxidation (reaction 2B), can easily react with O_2 to produce NO₂, which acts as oxidizing agent and increases the layer resistance. At high temperature the NO₂ oxidizing effect succeeds, while at a low temperature, being the conversion of NH₃ to NO less favored, the NH₃ reducing effect prevails [32].

In order to better describe the sensitivity towards NH_3 , the electrical response of all layers is reported as a function of NH_3 concentration at several operating temperatures (Fig. 8). At each temperature, layers generally easily detect the different concentrations of ammonia.

Pt-doped WO₃ layers showed the best performances at all temperatures. The reason for the higher electrical sensitivity of Pt-doped WO₃, with respect to Cr-doped, cannot be attributed only to higher amounts of electrons trapped by positive Pt center expected from the sensitization mechanism (3). Instead it can be also related to the presence of the Pt nanoparticles, revealed by HRTEM analysis. Following a recent literature suggestion, these finely distributed Pt particles may act as catalysts of the interaction between ammonia and O_o centers [33], decreasing the activation barrier in the reaction 1 and promoting the dissociation of the N–H bond.

Even if much lower than Pt-doped WO₃ sensors, the electrical response of Cr-doped WO₃ layers is always higher than pure WO₃, in particular at 275 °C (onset on Fig. 8a). This confirms that the doping with chromium



Fig. 8 Comparison among the electrical responses of Pt-doped, Crdoped and pure WO₃ films as a function of ammonia concentration in dry air at different temperatures: **a** 250 °C, **b** 275 °C, **c** 300 °C. *Insets* in **a**, **b** and **c** highlight the differences between undoped and Cr-doped sensor responses which are difficult to appreciate in the full scale

anyhow improves the electrical response of WO₃ films. In fact, Cr(III) and Cr(V) centers detected by EPR, should accept the electrons injected by NH_3 (following reaction 3) decreasing their positive oxidation state and increasing the overall sensitivity.

The overall results suggest that the combination between mesoporous architecture and metal doping can really promote the electrical response of WO_3 toward ammonia.

However, it appears an open problem whether the morphology is less or more effective than the doping metal in influencing the electrical properties of metal oxide gas sensors. In fact, several investigations report about the sensing performance of oxides with different morphologies [26, 27, 30–32], mainly in the case of nanostructures, but only very few consider the comparison among transition metal-doped oxides having the same morphology [34]. Interestingly in the case of Cr-doped WO₃, it has been reported that the metal doping is able to quench the electrical differences due to two different nanostructures, and the electrical behavior is fully influenced by the dopant metal [34]. The results obtained in the present study for Crdoped WO₃ thin films seem therefore in line with this behavior: the higher electrical response induced by Pt than by Cr doping WO₃ with the same nanostructure can be mainly attributed to the different ability of two metals to undergo reduction. Thus, mechanistic effects related to chemisorption and gas diffusion in mesoporous oxide appear less determinant than the electronic differences between the two examined doping metals.

4 Conclusions

A fast one-step sol-gel procedure, based on the use of triblock copolymer as templating agent, was successfully applied to synthesize both undoped and Cr or Pt-doped WO_3 mesoporous thin films, to be employed as ammonia gas sensors.

The obtained films were constituted by aggregates of interconnected WO₃ nanocrystals (20–50 nm) separated by mesopores with dimensions ranging between 5 and 15 nm. The doping metals, Pt and Cr, resulted differently hosted in the WO₃ mesoporous matrix. Chromium is homogeneously dispersed in the oxide matrix, mainly as Cr(III) and Cr(V) centers, as revealed by EPR spectroscopy; instead platinum segregated as Pt (0) nanoparticles (4 nm) mainly included inside WO₃ nanocrystals. This was related to the expected easier reducibility of the Pt centers compared to the Cr ones in the presence of triblock copolymer template, and to the Pt aggregation into clusters moving through the channels of the WO₃ open perovskite structure.

The WO₃ semiconductor layers containing Pt nanoclusters revealed, upon exposure to NH₃, remarkable electrical responses, much higher than Cr-doped and undoped layers, particularly at low ammonia concentration (6.2 ppm). This behavior was attributed to the presence of Pt nanoparticles segregated inside the semiconductor matrix, which act as catalysts of the N–H bond cleavage, decreasing the activation barrier in the ammonia dissociation. This probably makes the major difference with the simple electron capture performed by the oxidized doping centers. Thus, the electrical properties of Pt and Cr-doped WO₃ thin films, can be mainly related to the different reducibility of the dopants.

The role of the mesoporous structure in influencing the chemisorption and the gas diffusion in the WO_3 matrix appears less decisive than the electronic differences between the two examined metals.

The overall results support the validity of this synthesis method to supply promising nanomaterials for the detection of ammonia even at low concentration.

Acknowledgments The Milano group gratefully acknowledges the financial support of the Cariplo Foundation of Milano. The authors also personally thank Davide Fumagalli for his support in the experimental part.

References

- Göpel W, Hesse J, Zemel JN (1991) Sensors. A comprehensive survey, vol 2: Chemical and biochemical sensors (Parts 1 and 2). VCH Weinheim, New York
- 2. Barsan SN, Bauer M, Weimar U (2001) Sens Actuators B 73: 1–26
- Göpel W, Hesse J, Zemel JN, Meixner H, Jones R (1995) Sensors. A comprehensive survey, vol 8. VCH Weinheim, New York
- 4. Moseley PT, Tofield BC (1987) Solid- state gas sensors. Hilger, Bristol/Philadelphia
- Sberveglieri G (1992) Gas sensors: principles, operation and developments. Kluwer, Boston
- Mandelis A, Christofides C (1993) Physics, chemistry and technology of solid state gas sensor devices. Wiley, New York
- 7. Cui Y, Wie Q, Park H, Lieber CM (2001) Science 293: 1289–1292
- Xia Y, Yang P, Sun Y, Wu Y, Mayers B, Gates B, Yin Y, Kim F, Yan H (2003) Adv Mater 15:353–389
- 9. Lee JH (2009) Sens Actuators B 140:319-336

- Scott RWJ, Yang SM, Coombs N, Williams DE, Ozin GA (2003) Adv Funct Mater 13:225–231
- Acciarri M, Barberini R, Canevali C, Mari CM, Mattoni M, Morazzoni F, Nodari L, Polizzi S, Ruffo R, Russo U, Sala M, Scotti R (2005) Chem Mater 17:6167–6171
- Sasahara K, Hyodo T, Shimizu Y, Egashira M (2004) J Eur Ceram Soc 24:1961–1967
- Wang H, Liang J, Fan H, Xi B, Zhang M, Xiong S, Zhu Y, Qian Y (2008) J Solid State Chem 181:122–129
- Firooz AA, Mahjoub AR, Khodadadi AA (2009) Sens Actuators B 141:89–96
- D'Arienzo M, Armelao L, Cacciamani A, Mari CM, Polizzi S, Ruffo R, Scotti R, Testino A, Wahba L, Morazzoni F (2010) Chem Mater 22:4083–4089
- Choi WK, Song SK, Cho JS, Yoon YS, Choi D, Jung HJ, Koh SK (1997) Sens Actuators B 40:21–27
- Canevali C, Chiodini C, Morazzoni F, Scotti R, Bianchi CL (1997) J Mater Chem 7:997–1002
- Canevali C, Mari CM, Mattoni M, Morazzoni F, Nodari L, Ruffo R, Russo U, Scotti R (2005) J Phys Chem B 109:7195–7202
- 19. Niederberger M, Garnweitner G (2006) Chem Eur J 12: 7282–7302
- Polleux J, Gurlo A, Barsan N, Weimar U, Antonietti M, Niederberger M (2006) Angew Chem Int Ed 45:261–265
- Yang P, Zhao D, Margolese DI, Chmelka BF, Stucky GD (1998) Nature 396:152–155
- Bailey FE, Koleske JV (1990) Alkylene oxides and their polymers. Marcel Dekker, New York
- Pokhrel S, Simion CE, Teodorescu VS, Barsan N, Weimar U (2009) Adv Funct Mater 19:1767–1774
- 24. Xu C, Tamaki J, Miura N, Yamazoe N (1991) Sens Actuators B 3:147–155
- 25. Simon I, Barsan N, Bauer M, Weimar U (2001) Sens Actuators B 73:1–26
- Epifani M, Andreu T, Magaña CR, Díaz R, Arbiol J, Siciliano P, Morante JR (2010) Sens Actuators B 148:200–206
- Epifani M, Andreu T, Arbiol J, Diaz R, Siciliano P, Morante JR (2009) Chem Mater 21:5215–5221
- 28. Brunauer S, Emmet PH, Teller E (1938) J Am Chem Soc 60:309–319
- 29. Barret EP, Joyner LG, Halenda PP (1951) J Am Chem Soc 73:373–380
- Jimenez I, Centeno MA, Scotti R, Morazzoni F, Arbiol J, Cornet A, Morante JR (2004) J Mater Chem 14:2412–2420
- Morazzoni F, Scotti R, Origoni L, D'Arienzo M, Jimenez I, Cornet A, Morante JR (2007) Catalysis Today 126:169–176
- Zamani C, Casals O, Andreu T, Morante JR, Romano-Rodriguez A (2009) Sens Actuators B 140:557–562
- Mudiyanselage K, Trenary M, Meyer RJ (2007) J Phys Chem C 111:7127–7136
- Rossinyol E, Prim A, Pellicer E, Arbiol J, Hernández-Ramírez F, Peiró F, Cornet A, Morante JR, Solovyov LA, Tian B, Bo T, Zhao D (2007) Adv Funct Mater 17:1801–1806